

# Chapter 5 - Internal Memory

Reading: Section 5.1 on pp. 145-154

## Memory Basics

Early memory was made out of doughnut-shaped ferromagnetic loops called cores; thus, today, main memory is still referred to as core memory.

Cache memory is composed of SRAM (static RAM)

- faster
- more expensive
- less dense

Main memory is composed of DRAM (dynamic RAM)

- slower
- less expensive
- more dense

As we've seen, semiconductor memories share the following characteristics:

Two stable states exist to represent a zero or a one

They can be written to (at least once) to set the state

They can be read to sense the state

Most cells look like the following:

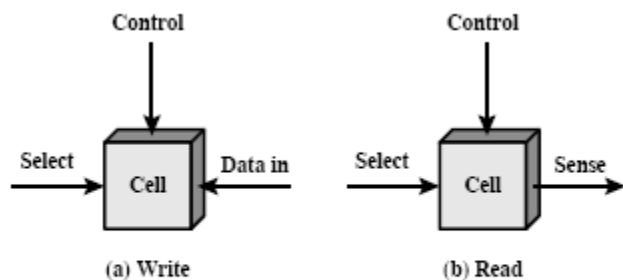


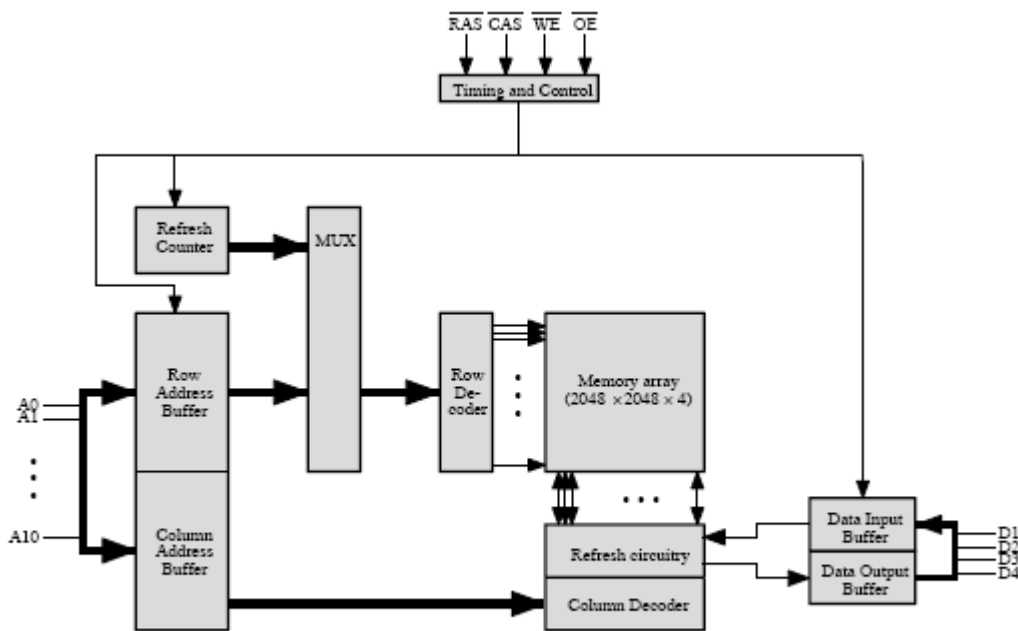
Figure 5.1 Memory Cell Operation

**Table 5.1 Semiconductor Memory Types**

Memory Type	Category	Erasure	Write Mechanism	Volatility
Random-access memory (RAM)	Read-write memory	Electrically, byte-level	Electrically	Volatile
Read-only memory (ROM)			Masks	
Programmable ROM (PROM)	Read-only memory	Not possible	Electrically	Nonvolatile
Erasable PROM (EPROM)				
Electrically Erasable PROM (EEPROM)				
Flash memory	Read-mostly memory	Electrically, block-level		

Chip Logic

Consider the following diagram:



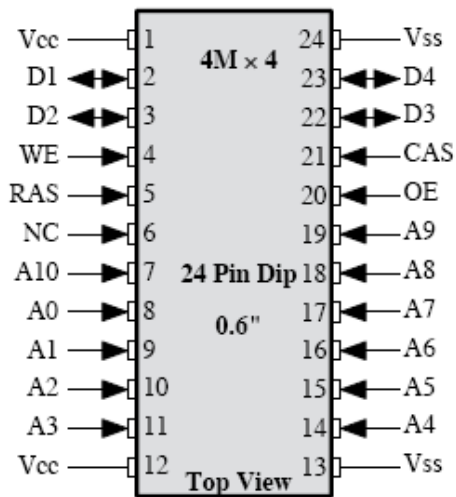
**Figure 5.3 Typical 16 Megabit DRAM (4M x 4)**

Q1: How many bits are read or written at a time?

Q2: How big is the bus used to access a memory location?

Q3: The address bus is multiplexed between the row select and then the column select. What does this mean?

Q4: Multiplexed addressing plus the use of square arrays result in a quadrupling of memory size for each additional pin. How would that apply to the above example? The chip for a 16Mbit DRAM might look like the following:

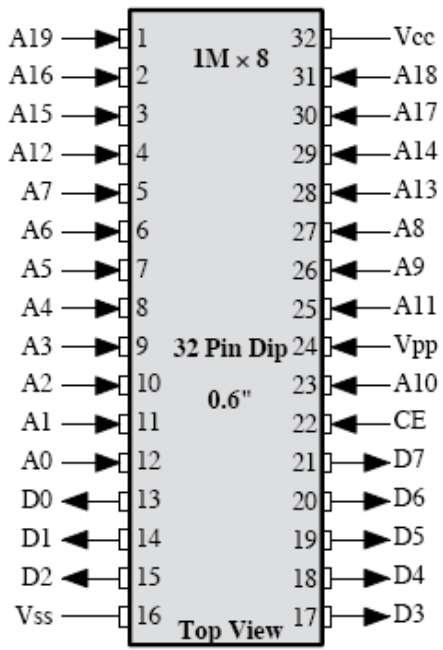


(b) 16 Mbit DRAM

"In [microelectronics](http://en.wikipedia.org/wiki/microelectronics), a **dual in-line package (DIP)**, sometimes called a **DIL** package, is an electronic device package with a rectangular housing and two parallel rows of electrical connecting pins, usually protruding from the longer sides of the package and bent downward. A DIP is usually referred to as a **DIP $n$** , where  $n$  is the total number of pins. For example, a microcircuit package with two rows of seven vertical leads would be a DIP14."

from [http://en.wikipedia.org/wiki/Dual\\_in-line\\_package](http://en.wikipedia.org/wiki/Dual_in-line_package)

The chip for an 8Mbit EPROM might look like:



(a) 8 Mbit EPROM